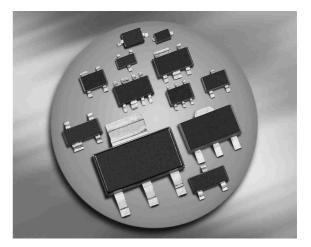


Silicon RF Switching Diode

- Low-loss VHF / UHF switch above 10 MHz
- PIN diode with low forward resistance
- Pb-free (RoHS compliant) package





BAT18-04

BAT18-05





Туре	Package	Configuration	L _S (nH)	Marking
BAT18-04	SOT23	series	1.8	AUs
BAT18-05	SOT23	common cathode	1.8	ASs

Maximum Ratings at $T_A = 25^{\circ}$ C, unless otherwise specified

Parameter	Symbol	Value	Unit	
Diode reverse voltage	V _R	35	V	
Forward current	I _F	100	mA	
Junction temperature	Ti	150	°C	
Operating temperature range	T _{op}	-55 125		
Storage temperature	T _{stq}	-55 150		

Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point ¹⁾	R _{thJS}	≤ 290	K/W
BAT18-04, BAT18-05			

¹For calculation of R_{thJA} please refer to Application Note Thermal Resistance



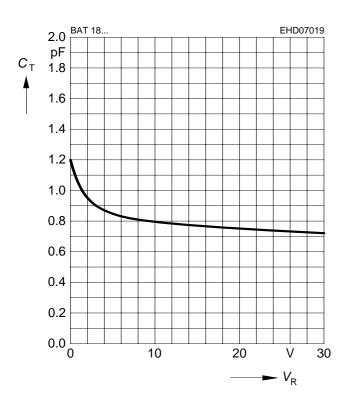
Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Reverse current	I _R				nA
<i>V</i> _R = 20 V		-	-	20	
$V_{\rm R}$ = 20 V, $T_{\rm A}$ = 60 °C		-	-	200	
Forward voltage	V _F	-	0.92	1.2	V
<i>I</i> _F = 100 mA					
AC Characteristics					
Diode capacitance	CT	-	0.75	1	pF
V _R = 20 V, <i>f</i> = 1 MHz					
Forward resistance	r _f	-	0.4	0.7	Ω
<i>I</i> _F = 5 mA, <i>f</i> = 100 MHz					
Charge carrier life time	τ _{rr}	-	120	-	ns
$I_{\rm F}$ = 10 mA, $I_{\rm R}$ = 6 mA, measured at $I_{\rm R}$ = 3 mA ,					
<i>R</i> _L = 100 Ω					
I-region width	W	-	3	-	μm

Electrical Characteristics at $T_A = 25^{\circ}$ C, unless otherwise specified



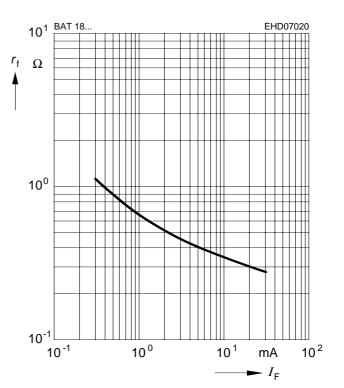
Diode capacitance $C_{T} = f(V_{R})$

f = 1 MHz

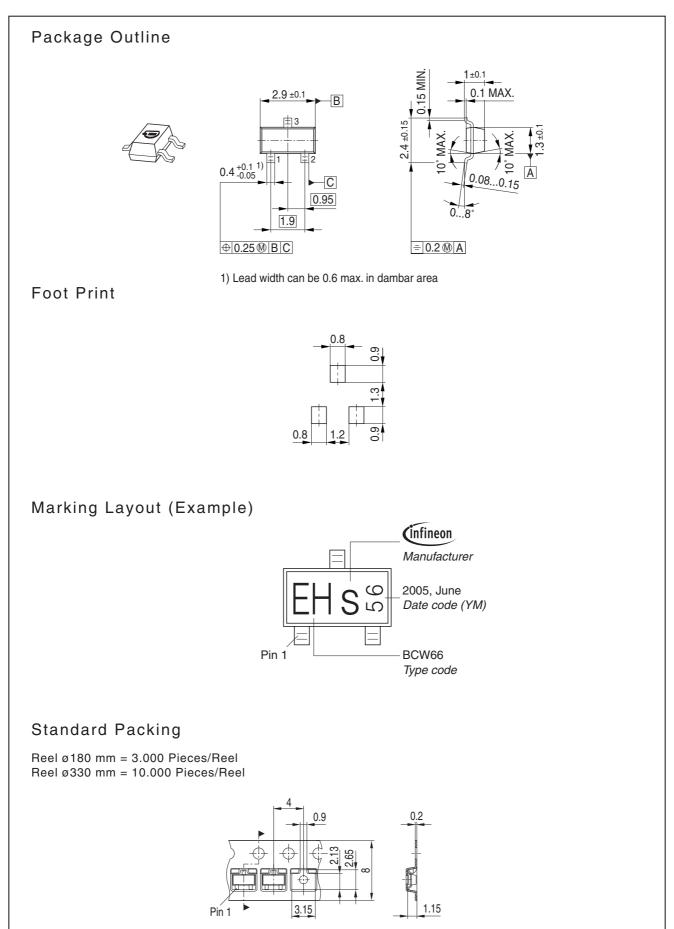


Forward resistance $r_{\rm f} = f (I_{\rm F})$

f = 100 MHz











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